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May 2007



**FJPF3305** 

### **High Voltage Switch Mode Application**

- High Speed Switching
- Suitable for Electronic Ballast and Switching Regulator



#### 1.Base 2.Collector 3.Emitter

### Absolute Maximum Ratings \* T<sub>a</sub> = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CBO}$	Collector-Base Voltage	700	V
V <sub>CEO</sub>	Collector-Emitter Voltage	400	V
V <sub>EBO</sub>	Emitter-Base Voltage	9	V
I <sub>C</sub>	Collector Current (DC)	4	A
I <sub>CP</sub>	Collector Current (Pulse)	8	A
I <sub>B</sub>	Base Current	2	A
P <sub>C</sub>	Collector Dissipation (T <sub>a</sub> = 25°C)	30	W
TJ	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	-65 ~ 150	°C

<sup>\*</sup> These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

## Electrical Characteristics ${}^{\star} T_C = 25^{\circ} C$ unless otherwise noted

Symbol	Parameter	Conditions	Min.	Тур.	Max	Units
BV <sub>CBO</sub>	Collector-Base Breakdwon Voltage	$I_C = 500\mu A, I_E = 0$	700			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	$I_{C} = 5mA, I_{B} = 0$	400			V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	$I_E = 500 \mu A, I_C = 0$	9			V
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> = 700V, I <sub>E</sub> = 0			1	μΑ
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = 9V, I_{C} = 0$			1	μΑ
h <sub>FE1</sub>	DC Current Gain *	$V_{CE} = 5V, I_{C} = 1A$ $V_{CE} = 5V, I_{C} = 2A$	19 8		35 40	
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	$I_C = 1A, I_B = 0.2A$ $I_C = 2A, I_B = 0.5A$ $I_C = 4A, I_B = 1A$			0.5 0.6 1.0	V V V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	$I_C = 1A, I_B = 0.2A$ $I_C = 2A, I_B = 0.5A$			1.2 1.6	V V
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CE} = 5V$ , $I_C = 1A$	4			MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = 10V, f = 1MHz		65		pF
t <sub>ON</sub>	Turn On Time	V <sub>CC</sub> = 125V			0.8	μS
t <sub>STG</sub>	Storge Time	$I_C = 2A = 5I_{B1} = -5I_{B2}$ $= R_1 = 62.5\Omega$			4.0	μS
t <sub>F</sub>	Fall Time	11 - 02.052			0.9	μS

<sup>\*</sup> Pulse Test: PW  $\leq 300 \mu s, \ \text{Duty Cycle} \leq 2\%$ 

# **h**<sub>FE</sub> Classification

Classification	H1	H2
h <sub>FE2</sub>	19 ~ 28	26 ~ 35

### **Typical Performance Characteristics**

Figure 1. Static Characteristic

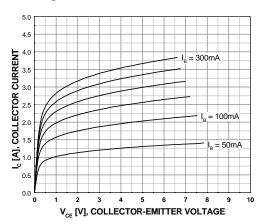


Figure 2. DC Current Gain (R-Grade)

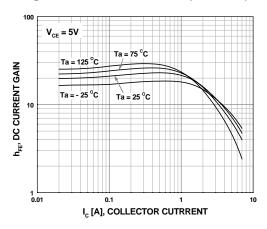


Figure 3. DC Current Gain (O-Grade)

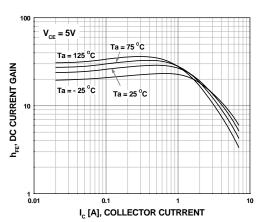


Figure 4. Saturation Voltage (R-Grade)

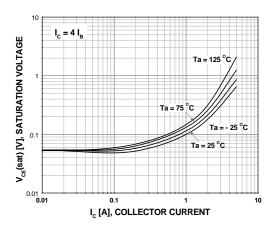


Figure 5. Saturatin Voltage (O-Grade)

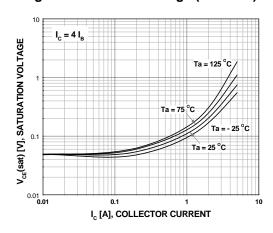
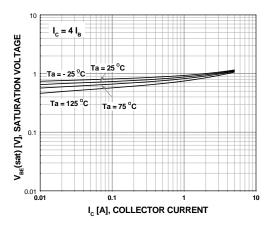


Figure 6. Saturation Voltage (R-Grade)



### Typical Performance Characteristics (Continued)

Figure 7. Saturation Voltage (O-Grade)

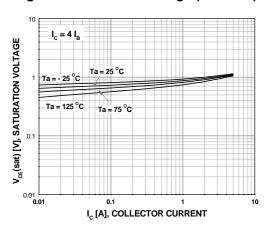


Figure 8. Switching Time

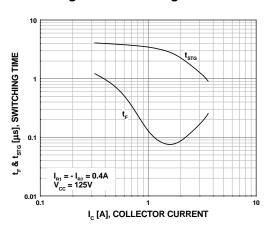


Figure 9. Reverse Biased Safe Operating Area Figure 10.

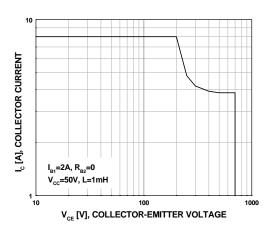


Figure 10. Forward Biased Safe Operating Area

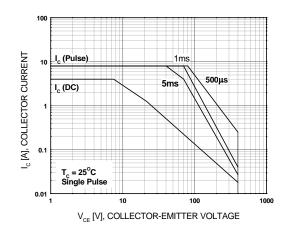
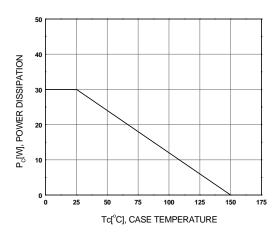
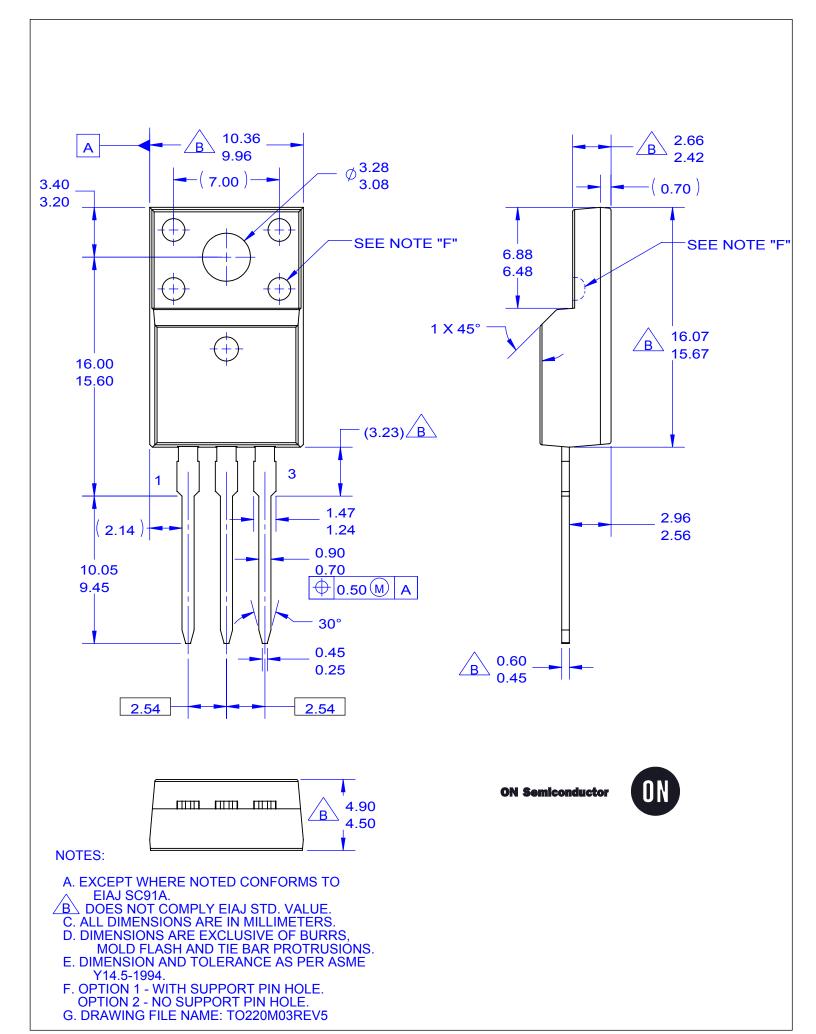


Figure 11. Power Derating





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